## One Cell Lithium-ion/Polymer Battery Protection IC

### **GENERAL DESCRIPTION**

JA5088SL is a spacing saving single chip lithium-ion/polymer battery protection IC. Integrating power MOSFET and only two external components makes the protection board highly compact. JA5088SL has full protection including over charging voltage protection, over discharging protection, over current protection, short protection and over temperature protection. The very low standby current drains little current from the cell while in storage. JA5088SL is available in 8 PIN SOP8\_ package.

### **FEATURES**

- ·Integrate low Rdson Power MOSFET
- ·SOP8\_Package
- ·Over-temperature Protection
- ·Two-steps Over current protection
- ·High-accuracy Voltage Detection
- ·Low Current Consumption
  - Operation Mode: 2.5µA typ.
- Power-down Mode: 0.1µA typ.

RoHS Compliant and Lead (Pb) Free

### **APPLICATIONS**

One-Cell Lithium-ion Battery Pack Lithium-Polymer Battery Pack

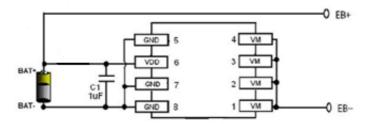


Figure 1. Typical Application Circuit

### DESCRIPTION

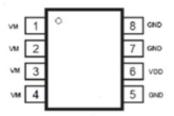


Figure 2. PIN Configuration

Number	Name	Description
1,2,3,4	VM	The negative terminal of the battery pack. The internal FET switch connects this terminal to GND
5,7,8	GND	Ground, connect the negative terminal of the battery to this pin
6	VDD	Power Supply

## ORDERING INFORMATION

PART NUMBE R	Pa ck ag e	Overcharg e Detection Voltage [VCU] (V)	Overchar ge Release Voltage [VCL] (V)	Overdischar ge Detection Voltage [VDL] (V)	Overdischar ge Release Voltage [VDR] (V)	Overcurr ent Detection Current [IOV1] (A)	Top Mark
JA5088SL	S O P8	4.28	4.10	2.40	3.0	(6-7)	JA5088SL

# Function Block Diagram

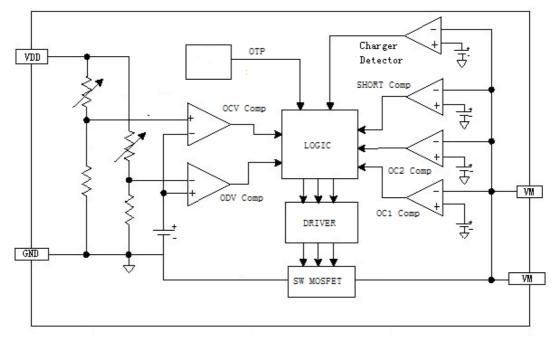


Figure 3. Functional Block Diagram

## ABSOLUTE MAXIMUM RATINGS

(Note: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

PARAMETER	VALUE	UNIT
VDD input pin voltage	-0.3 to 6	V
VM input pin voltage	-6 to 18	V
Operating Ambient Temperature	-40 to 85	°C
Maximum Junction Temperature	125	°C
Storage Temperature	-55 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C
Power Dissipation at T=25 °C	0.4	W
Package Thermal Resistance (Junction to Ambient) θJA	250	°C/W
Package Thermal Resistance (Junction to Case) θJC	130	°C/W
ESD	2000	V

## ABSOLUTE MAXIMUM RATINGS

Typically  $T_A = 27^{\circ}C$ , VDD=3.7V unless otherwise specified

Parameter	Symbo I	Test Condition	M in	T y p	M ax	Unit
Detection Voltage						
Overcharge Protection Voltage	V <sub>ocv</sub>		4.275	4.30	4.375	V
Overcharge Protection Release Voltage	V <sub>OCR</sub>		4.10	4.15	4.22	V
Overdischarge Protection Voltage	V <sub>ODV</sub>		2.3	2.4	2.5	V
Overdischarge Protection Release Voltage	V <sub>ODR</sub>		2.9	3.0	3.1	V
Charger Detection Voltage	V <sub>CHA</sub>		-0.07	-0.12	-0.2	V
Detection Current						
Class1 Overdischarge Protection Current	I <sub>OCI1</sub>			6		А
Class2 Overdischarge Protection Current	I <sub>OCI2</sub>			14		А
Load Short-Circuiting	I SHORT			21		А

Detection						
Overcharge Protection Current	I <sub>CHA</sub>		4	7	10	Α
Current Consumption						
Current Consumption in Normal Operation	I <sub>OPE</sub>	V <sub>D`D</sub> =3.9V VM =0V		2.5		μ A
Current Consumption in power Down	I PDN	V <sub>DD</sub> =2.0V VM pin floating		0.1		μ A
VM Internal Resistance						
Internal Resistance between VM and V <sub>DD</sub>	R <sub>VMD</sub>	V <sub>D</sub> =3.5V VM=1.0V		320		kΩ
Internal Resistance between VM and GND	R <sub>VMS</sub>	V <sub>DD</sub> =2.0V VM=1.0V		100		kΩ
FET on Resistance			•		1	
Equivalent FET on Resistance	R <sub>DS(ON)</sub>	V <sub>DD</sub> =3.6V I <sub>VM</sub> =1.0A		22		mΩ
Over Temperature Protection						
Over Temperature Protection	T <sub>SHD+</sub>			140		°C
Over Temperature Recovery Degree	T <sub>SHD-</sub>			100		°C
Detection Delay Time						
Overcharge Voltage Detection	t <sub>ocv</sub>			130		mS
Delay Time						
Overdischarge Voltage Detection Delay Time	t <sub>ODV</sub>			40		mS
Overdischarge Current1 Delay Time	t <sub>IOV1</sub>			10		mS
Overdischarge Current2 Delay Time	t <sub>IOV2</sub>			5		mS
Load Short- Circuiting Detection Delay Time	t <sub>SHORT</sub>	Vdd=3.5V		75		uS

# Description of Operation

Overcharge Protection
When the voltage of the battery cell exceeds

the overcharge protection voltage (Vocv) beyond the overcharge delay time (tocv) period, charging is inhibited by turning off power MOSFET. The overcharge condition is

released in two cases:

- 1. The voltage of the battery cell becomes lower than the overcharge release voltage (Vocr) through self-discharge.
- 2. The voltage of the battery cell falls below the overcharge protection voltage (Vocv) and a load is connected. When the battery voltage is above Vocv, the overcharge condition will not release even a load is connected to the pack.

### Overdischarge Protection

When the voltage of the battery cell goes below the overdischarge protection voltage (V<sub>ODV</sub>) beyond the overdischarge delay time (<sup>t</sup>ODV) period, discharging is inhibited. Inhibition of discharging is immediately released when the voltage of the battery cell becomes higher than overdischarge release voltage (Vodr).

#### Overcurrent Protection

When the discharging current becomes higher than a specified Overdischarge Current and beyond over discharge current delay time period, discharging is inhibited. Inhibition of discharging is immediately released when the load is released or the impedance between EB+ and EB- is larger than 500kΩ. The JA5088SL provides three over current detection levels (8A, 14A and 36A) with three over current delay time (tlov1, tlov2 and tshort) corresponding to each over current detection level.

#### Over Temperature Protection

When IC temperature becomes higher than a specified value, JA5088SL will turn off Power MOSFET whatever in discharging or charging condition. In discharging condition, Inhibition of discharging is released when temperature lower than Over Temperature Recovery Degree (100 °C) and load also released. In charging condition, Inhibition of charging is released when temperature lower than over temperature recovery degree(100 °C) and charger also

removed.

Over Charging Current Protection When the charging current becomes higher than discharge protection Current (<sup>I</sup>CHA) and beyond over discharge current delay time period, charging is inhibited. Inhibition of charging is immediately released when the charger is removed.

Charger detection after Overdischarge When over discharge occurs, discharging is inhibited. However, charging is still permitted through the parasitic diode of MOSFET. Once the charger is connected to the battery pack, JA5088SL detects the voltage between VM and GND is below charge detection threshold voltage (VCHA), Power MOSFET will turn on when Battery cell voltage is higher than Overdischarge Protection Voltage.

Power Saving after Overdischarge When overdischarge occurs, the JA5088SL will enter into power-down mode.

### **Timing Diagram**

3. Over Discharge Current (ODC)State →Normal State

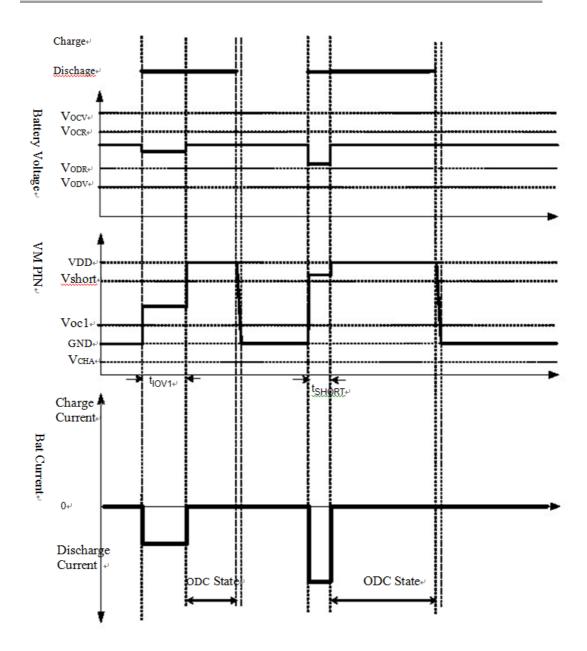


Figure 6. Over Discharge current and Normal state timing

### TYPICAL APPLICATION

As shown in Figure 7, the bold line is the high density current path which must be kept as short as possible. For thermal management, ensure that these trace widths are adequate. C1 is a decoupling capacitor which should be placed as close as possible to JA5088SL.

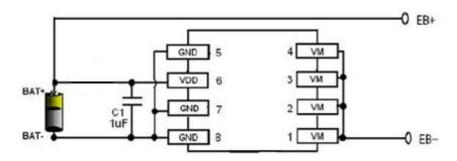


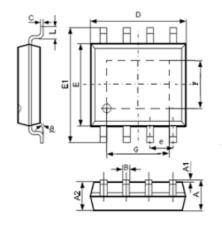
Figure 7. Typical Battery Protection Circuit

### **Precautions**

- Pay attention to the operating conditions for input/output voltage and load current so that the power loss in JA5088SL does not exceed the power dissipation of the package.
- Do not apply an electrostatic discharge to this JA5088SL that exceeds the performance ratings of the built-in electrostatic protection circuit.

## PACKAGE OUTLINE

### SOP8\_ PACKAGE OUTLINE AND DIMENSIONS



SYMBOL	Dimen	sion in	Dimen	sion in
	Millim	eters	Inc	hes
	MIN	MAX	MIN	MAX
Α	1.35	1.75	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
В	0.330	0.510	0.013	0.020
С	0.190	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
е	1.27	TYP	0.050	TYP
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°
F	2.26	2.56	0.089	0.101
G	3.15	3.45	0.124	0.136

